Bipolar Transistors Silicon NPN Epitaxial Type (PCT Process)(Bias Resistor built-in Transistor)

RN1114/15/16/17/18

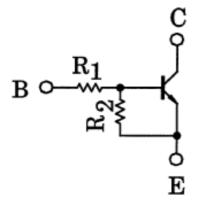
1. Applications

- Switching
- Inverter Circuits
- Interfacing
- Driver Circuits

2. Features

- (1) AEC-Q101 qualified (Please see the orderable part number list)
- (2) The integrated bias resistor reduces the number of external parts required, making it possible to reduce system size and assembly time.
- (3) Toshiba offers transistors with a wide range of resistance to accommodate various circuit designs.
- (4) Complementary to RN2114 to RN2118

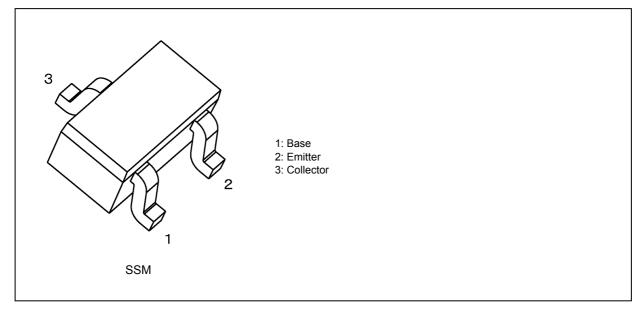
3. Equivalent Circuit



4. Bias Resistor Values

Part No.	R1 (kΩ)	R2 (kΩ)
RN1114	1	10
RN1115	2.2	10
RN1116	4.7	10
RN1117	10	4.7
RN1118	47	10

5. Packaging and Pin Assignment



6. Orderable part number

Orderable part number		AEC-Q101	Note	Note	
RN1114	RN1114,LF	_		General Use	
	RN1114,LXGF	YES	(Note 1)	Unintended Use	(Note 1)
RN1115	RN1115,LF	_		General Use	
	RN1115,LXGF	YES	(Note 1)	Unintended Use	(Note 1)
	RN1115,LXHF	YES		Automotive Use	
RN1116	RN1116,LF	_		General Use	
	RN1116,LXGF	YES	(Note 1)	Unintended Use	(Note 1)
	RN1116,LXHF	YES		Automotive Use	
RN1117	RN1117(TE85L,F)	_		General Use	
	—	YES	(Note 1)	Unintended Use	(Note 1)
RN1118	RN1118(TE85L,F)	—		General Use	
	—	YES	(Note 1)	Unintended Use	(Note 1)

Note 1: For more information, please contact our sales or use the inquiry form on our website.

7. Absolute Maximum Ratings (Note) (Unless otherwise specified, $T_a = 25$ °C)

Characteris	Symbol	Rating	Unit	
Collector-base voltage	RN1114~RN1118	V _{CBO}	50	V
Collector-emitter voltage		V _{CEO}	50	1
Emitter-base voltage	RN1114	V _{EBO}	5	V
	RN1115		6	1
	RN1116		7	1
	RN1117]	15	1
	RN1118	1	25	1
Collector current	RN1114~RN1118	Ι _C	100	mA
Collector power dissipation		Pc	100	mW
Junction temperature		Tj	150	°C
Storage temperature		T _{stg}	-55 to 150	1

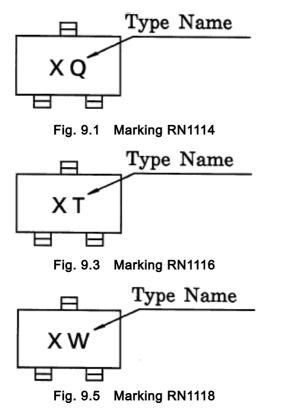
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

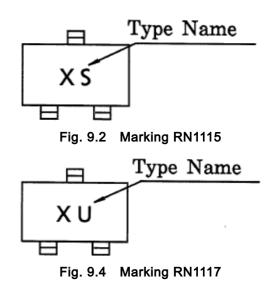
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

8. Electrical Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	RN1114~	I _{CBO}	V _{CB} = 50 V, I _E = 0 mA	1		100	nA
	RN1118	I _{CEO}	V _{CE} = 50 V, I _B = 0 mA	—	_	500	
Emitter cut-off current	RN1114	I _{EBO}	V _{EB} = 5 V, I _C = 0 mA	0.35		0.65	mA
	RN1115		V _{EB} = 6 V, I _C = 0 mA	0.37		0.71	
	RN1116		V _{EB} = 7 V, I _C = 0 mA	0.36	_	0.68	
	RN1117		V _{EB} = 15 V, I _C = 0 mA	0.78	_	1.46	
	RN1118		V _{EB} = 25 V, I _C = 0 mA	0.33	—	0.63	
DC current gain	RN1114 ~ RN1116, RN1118	h _{FE}	V _{CE} = 5 V, I _C = 10 mA	50	—	—	—
	RN1117			30	_	_	
Collector-emitter saturation voltage	RN1114~ RN1118	V _{CE(sat)}	I _C = 5 mA, I _B = 0.25 mA	—	0.1	0.3	V
Input voltage (ON)	RN1114	V _{I(ON)}	V _{CE} = 0.2 V, I _C = 5 mA	0.6		2.0	V
	RN1115			0.7		2.5	
	RN1116			0.8		2.5	
	RN1117			1.5		3.5	
	RN1118			2.5	_	10.0	
Input voltage (OFF)	RN1114	V _{I(OFF)}	V _{CE} = 5 V, I _C = 0.1 mA	0.3		0.9	V
	RN1115			0.3		1.0	
	RN1116			0.3	_	1.1	
	RN1117			0.3	—	2.3	
	RN1118			0.5	—	5.7	
Transition frequency	RN1114~ RN1118	f _T	V _{CE} = 10 V, I _C = 5 mA	_	250	_	MHz
Collector output capacitance	RN1114~ RN1118	C _{ob}	V _{CB} = 10 V, I _E = 0 mA, f = 1 MHz	—	3.0	6.0	pF
Input resistance	RN1114	R ₁	_	0.7	1.0	1.3	kΩ
	RN1115			1.54	2.2	2.86	
	RN1116			3.29	4.7	6.11	
	RN1117			7.0	10.0	13.0	
	RN1118			32.9	47.0	61.1	
Resistor ratio	RN1114	R1/R2	_	_	0.1	_	—
	RN1115			_	0.22	_	
	RN1116			_	0.47	_	
	RN1117			_	2.13	_	
	RN1118			_	4.7	_	

9. Marking





10. Characteristics Curves (Note)

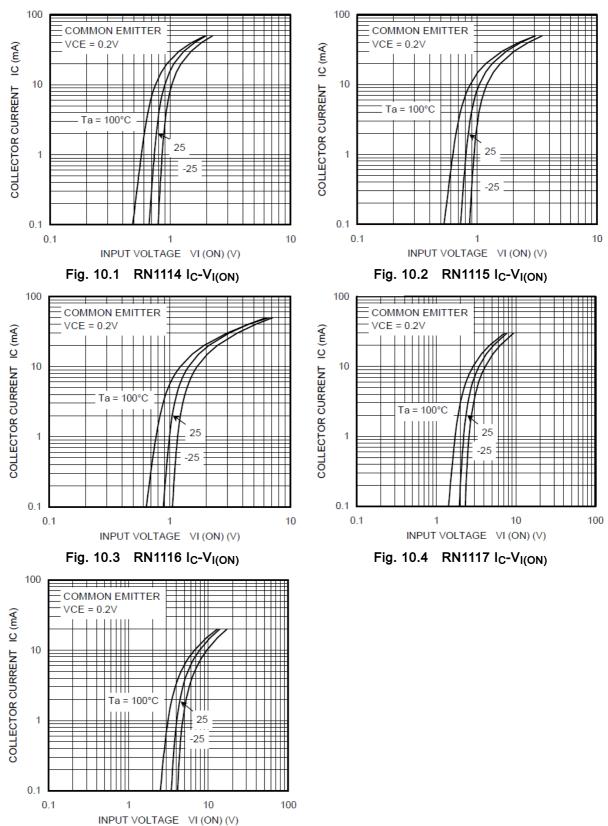


Fig. 10.5 RN1118 I_C-V_{I(ON)}



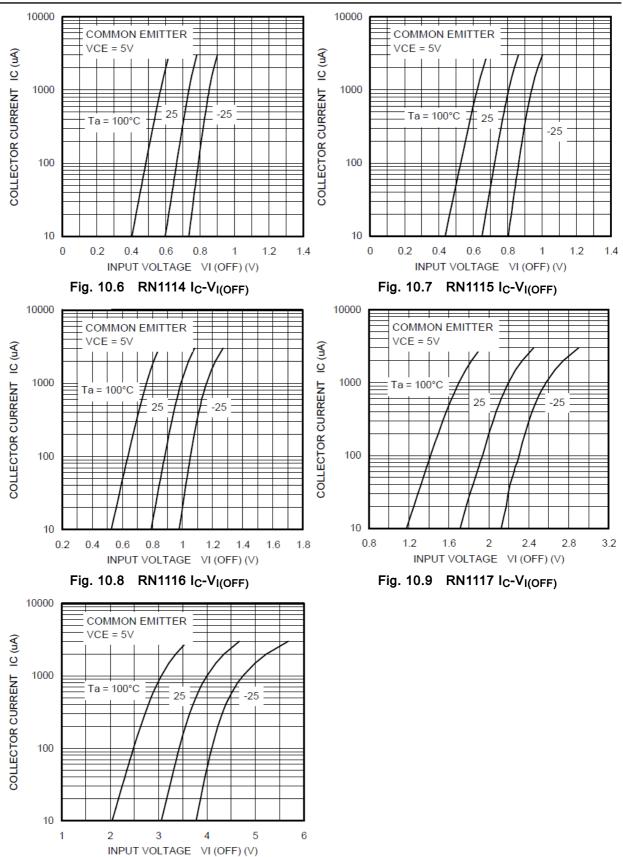


Fig. 10.10 RN1118 IC-VI(OFF)



RN1114 to RN1118

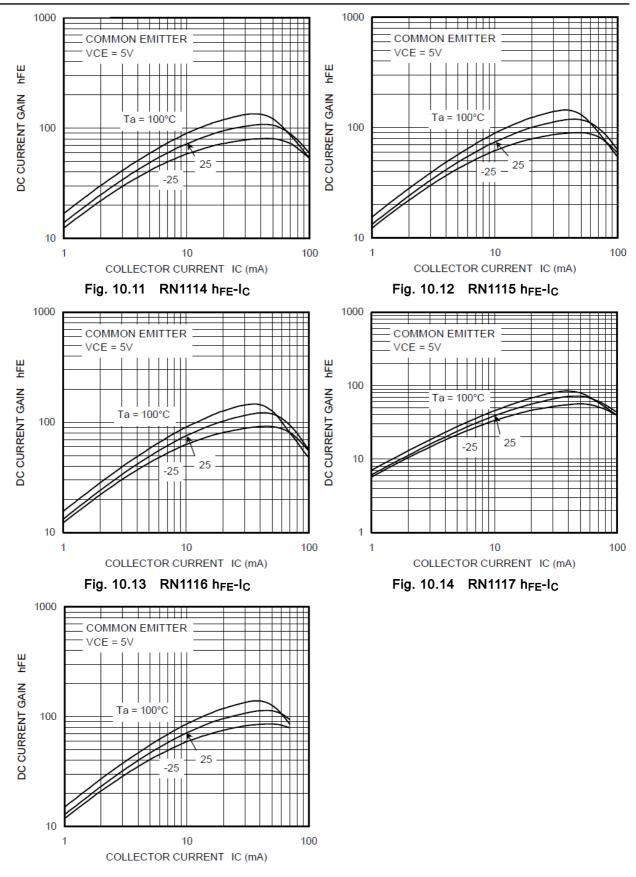
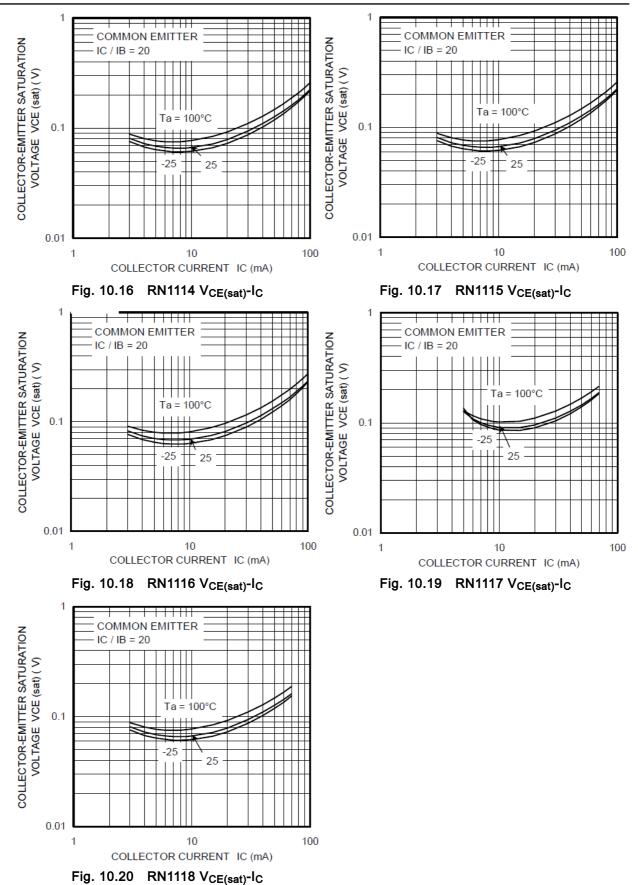


Fig. 10.15 RN1118 h_{FE}-I_C



RN1114 to RN1118

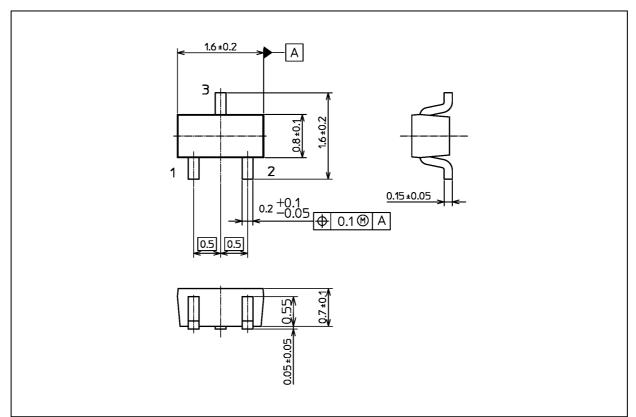


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



Package Dimensions

Unit: mm



Weight: 2.4 mg (typ.)

	Package Name(s)
TOSHIBA: 2-2H1S	
Nickname: SSM	

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